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# **DUAL LOW-NOISE OPERATIONAL AMPLIFIERS**

### **FEATURES**

 Equivalent Input Noise Voltage: 5 nV/√Hz Typ at 1 kHz

• Unity-Gain Bandwidth: 10 MHz Typ

Common-Mode Rejection Ratio: 100 dB Typ

• High DC Voltage Gain: 100 V/mV Typ

• Peak-to-Peak Output Voltage Swing 26 V Typ

With  $V_{CC\pm} = \pm 15 \text{ V}$  and  $R_L = 600 \Omega$ 

High Slew Rate: 9 V/μs Typ

### 

### **DESCRIPTION/ORDERING INFORMATION**

The NE5532, NE5532A, SA5532, and SA5532A are high-performance operational amplifiers combining excellent dc and ac characteristics. They feature very low noise, high output-drive capability, high unity-gain and maximum-output-swing bandwidths, low distortion, high slew rate, input-protection diodes, and output short-circuit protection. These operational amplifiers are compensated internally for unity-gain operation. These devices have specified maximum limits for equivalent input noise voltage.

### ORDERING INFORMATION(1)

T <sub>A</sub>	PAC	(AGE <sup>(2)</sup>	ORDERABLE PART NUMBER	TOP-SIDE MARKING	
	PDIP – P	Tube of 50	NE5532P	NE5532P	
	FDIF - F	Tube of 50	NE5532AP	NE5532AP	
0℃ to 70℃		Tube of 75	NE5532D	NEECO	
	SOIC - D	Reel of 2500	NE5532DR	N5532	
00.10700	SOIC - D	Tube of 75	NE5532AD	N5532A	
		Reel of 2500	NE5532ADR	N0002A	
	SOP – PS	Reel of 2000	NE5532PSR	N5532	
	30P - P3	Reel of 2000	NE5532APSR	N5532A	
	PDIP – P	Tube of 50	SA5532P	SA5532P	
	FDIF - F	Tube of 50	SA5532AP	SA5532AP	
–40℃ to 85℃		Tube of 75	SA5532D	SA5532	
-40 C 10 65 C	SOIC - D	Reel of 2500	SA5532DR	SA0002	
	3010 - D	Tube of 75	SA5532AD	- SA5532A	
		Reel of 2500	SA5532ADR	SAUUSZA	

<sup>(1)</sup> For the most current package and ordering information, see the Package Option Addendum at the end of this document, or see the TI web site at www.ti.com.



Please be aware that an important notice concerning availability, standard warranty, and use in critical applications of Texas Instruments semiconductor products and disclaimers thereto appears at the end of this data sheet.

<sup>(2)</sup> Package drawings, thermal data, and symbolization are available at www.ti.com/packaging.



# 36 pF 37 pF 15 Ω OUT 15 Ω

**SCHEMATIC (EACH AMPLIFIER)** 

Component values shown are nominal.

460  $\Omega$ 

# **ABSOLUTE MAXIMUM RATINGS**(1)

over operating free-air temperature range (unless otherwise noted)

V	Supply valtage (2)	V <sub>CC+</sub>	22 V
$V_{CC}$	Supply voltage (2)	V <sub>CC</sub> -	–22 V
	Input voltage, either input (2)(3)		V <sub>CC±</sub>
	Input current <sup>(4)</sup>		±10 mA
	Duration of output short circuit (5)		Unlimited
		D package	97℃/W
$\theta_{JA}$	Package thermal impedance (6)(7)	P package	85℃/W
		PS package	95℃/W
TJ	Operating virtual-junction temperature		150℃
T <sub>stg</sub>	Storage temperature range		–65℃ to 150℃

- (1) Stresses beyond those listed under "absolute maximum ratings" may cause permanent damage to the device. These are stress ratings only, and functional operation of the device at these or any other conditions beyond those indicated under "recommended operating conditions" is not implied. Exposure to absolute-maximum-rated conditions for extended periods may affect device reliability.
- (2) All voltage values, except differential voltages, are with respect to the midpoint between V<sub>CC+</sub> and V<sub>CC-</sub>.
- (3) The magnitude of the input voltage must never exceed the magnitude of the supply voltage.
- (4) Excessive input current will flow if a differential input voltage in excess of approximately 0.6 V is applied between the inputs, unless some limiting resistance is used.
- (5) The output may be shorted to ground or either power supply. Temperature and/or supply voltages must be limited to ensure the maximum dissipation rating is not exceeded.
- (6) The package thermal impedance is calculated in accordance with JESD 51-7.
- (7) Maximum power dissipation is a function of  $T_J(max)$ ,  $\theta_{JA}$ , and  $T_A$ . The maximum allowable power dissipation at any allowable ambient temperature is  $P_D = (T_J(max) T_A)/\theta_{JA}$ . Operating at the absolute maximum  $T_J$  of 150°C can affect reliability.



### RECOMMENDED OPERATING CONDITIONS

			MIN	MAX	UNIT
V <sub>CC+</sub>	Supply voltage		5	15	V
V <sub>CC</sub> -	Supply voltage		<b>-</b> 5	-15	V
_	NE5532, NE5532/	١	0	70	3
T <sub>A</sub>	Operating free-air temperature SA5532, SA5532A		-40	85	C

### **ELECTRICAL CHARACTERISTICS**

 $V_{CC\pm} = \pm 15 \text{ V}, T_A = 25 \text{ C} \text{ (unless otherwise noted)}$ 

	PARAMETER	TEST COND	DITIONS <sup>(1)</sup>	MIN	TYP	MAX	UNIT
	hand effect well-ne	V 0	T <sub>A</sub> = 25℃		0.5	4	
$V_{IO}$	Input offset voltage	$V_O = 0$	T <sub>A</sub> = Full range <sup>(2)</sup>			5	mV
	lanut offect current	T <sub>A</sub> = 25℃	<u> </u>		10	150	~ A
I <sub>IO</sub>	Input offset current	T <sub>A</sub> = Full range <sup>(2)</sup>				200	nA
	Input bigg current	T <sub>A</sub> = 25℃			200	800	nA
I <sub>IB</sub>	Input bias current	T <sub>A</sub> = Full range <sup>(2)</sup>				1000	IIA
$V_{ICR}$	Common-mode input-voltage range			±12	±13		٧
$V_{OPP}$	Maximum peak-to-peak output-voltage swing	$R_L \ge 600 \Omega$ , $V_{CC\pm} = \pm 15 V$		24	26		V
		D > 600 O V	T <sub>A</sub> = 25℃	15	50		
٨	Large-signal differential-voltage	$R_L \ge 600 \Omega$ , $V_O = \pm 10 V$	T <sub>A</sub> = Full range <sup>(2)</sup>	10			V/mV
$A_{VD}$	amplification	D > 2 kO \/ .40 \/	T <sub>A</sub> = 25℃	25	100		
		$R_L \ge 2 k\Omega, V_{O} \pm 10 V$	T <sub>A</sub> = Full range <sup>(2)</sup>	15			
$A_{\text{vd}}$	Small-signal differential-voltage amplification	f = 10 kHz			2.2		V/mV
B <sub>OM</sub>	Maximum output-swing bandwidth	$R_L = 600 \Omega, V_O = \pm 10 V$			140		kHz
B <sub>1</sub>	Unity-gain bandwidth	$R_L = 600 \Omega, C_L = 100 pF$			10		MHz
r <sub>i</sub>	Input resistance			30	300		kΩ
Z <sub>O</sub>	Output impedance	$A_{VD} = 30 \text{ dB}, R_{L} = 600 \Omega, f$	= 10 kHz		0.3		Ω
CMRR	Common-mode rejection ratio	$V_{IC} = V_{ICR} \min$		70	100		dB
k <sub>SVR</sub>	Supply-voltage rejection ratio $(\Delta V_{CCz}/\Delta V_{IO})$	$V_{CC\pm} = \pm 9 \text{ V to } \pm 15 \text{ V, V}_{O} =$	0	80	100		dB
Ios	Output short-circuit current			10	38	60	mA
I <sub>CC</sub>	Total supply curent	V <sub>O</sub> = 0, No load			8	16	mA
	Crosstalk attenuation (V <sub>O1</sub> /V <sub>O2</sub> )	V <sub>01</sub> = 10 V peak, f = 1 kHz			110		dB

 <sup>(1)</sup> All characteristics are measured under open-loop conditions, with zero common-mode input voltage, unless otherwise specified.
 (2) Full temperature ranges are: −40℃ to 85℃ for the SA5532 and SA5532A, and 0℃ to 70℃ for the NE5532 and NE5532A.



### **OPERATING CHARACTERISTICS**

 $V_{CC\pm} = \pm 15 \text{ V}, T_A = 25\%$  (unless otherwise noted)

	PARAMETER	TEST CONDITIONS	NE55	32, SA5	532	NE553	UNIT			
	PARAMETER	TEST CONDITIONS	MIN	TYP	MAX	MIN	IIN TYP MAX		ONIT	
SR	Slew rate at unity gain			9			9		V/µs	
	Overshoot factor	$V_{I} = 100 \text{ mV}, R_{L} = 600 \Omega,$ $A_{VD} = 1, C_{L} = 100 \text{ pF}$		10			10		%	
\/	Equivalent input noise voltage	f = 30 Hz		8			8	10	nV/√ <del>Hz</del>	
V <sub>n</sub>	Equivalent input noise voltage	f = 1 kHz		5			5	6	IIV/ VIIZ	
	Facilizations in put poince ourrent	f = 30 Hz		2.7			2.7		5 \ \s\ <del>\</del>	
In	Equivalent input noise current	f = 1 kHz		0.7			0.7		pA/√Hz	





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### **PACKAGING INFORMATION**

Orderable Device	Status	Package Type	Package Drawing	Pins	Package Qty	Eco Plan	Lead/Ball Finish	MSL Peak Temp	Op Temp (°C)	Device Marking (4/5)	Samples
NE5532AD	ACTIVE	SOIC	D	8	75	Green (RoHS & no Sb/Br)	CU NIPDAU	Level-1-260C-UNLIM	0 to 70	N5532A	Samples
NE5532ADE4	ACTIVE	SOIC	D	8	75	Green (RoHS & no Sb/Br)	CU NIPDAU	Level-1-260C-UNLIM	0 to 70	N5532A	Samples
NE5532ADR	ACTIVE	SOIC	D	8	2500	Green (RoHS & no Sb/Br)	CU NIPDAU	Level-1-260C-UNLIM	0 to 70	N5532A	Samples
NE5532ADRE4	ACTIVE	SOIC	D	8	2500	Green (RoHS & no Sb/Br)	CU NIPDAU	Level-1-260C-UNLIM	0 to 70	N5532A	Samples
NE5532ADRG4	ACTIVE	SOIC	D	8	2500	Green (RoHS & no Sb/Br)	CU NIPDAU	Level-1-260C-UNLIM	0 to 70	N5532A	Samples
NE5532AIP	OBSOLETI	PDIP	Р	8		TBD	Call TI	Call TI	-40 to 85		
NE5532AP	ACTIVE	PDIP	Р	8	50	Pb-Free (RoHS)	CU NIPDAU	N / A for Pkg Type	0 to 70	NE5532AP	Samples
NE5532APE4	ACTIVE	PDIP	Р	8	50	Pb-Free (RoHS)	CU NIPDAU	N / A for Pkg Type	0 to 70	NE5532AP	Samples
NE5532APSR	ACTIVE	so	PS	8	2000	Green (RoHS & no Sb/Br)	CU NIPDAU	Level-1-260C-UNLIM	0 to 70	N5532A	Samples
NE5532APSRE4	ACTIVE	SO	PS	8	2000	Green (RoHS & no Sb/Br)	CU NIPDAU	Level-1-260C-UNLIM	0 to 70	N5532A	Samples
NE5532D	ACTIVE	SOIC	D	8	75	Green (RoHS & no Sb/Br)	CU NIPDAU	Level-1-260C-UNLIM	0 to 70	N5532	Samples
NE5532DG4	ACTIVE	SOIC	D	8	75	Green (RoHS & no Sb/Br)	CU NIPDAU	Level-1-260C-UNLIM	0 to 70	N5532	Samples
NE5532DR	ACTIVE	SOIC	D	8	2500	Green (RoHS & no Sb/Br)	CU NIPDAU   CU SN	Level-1-260C-UNLIM	0 to 70	N5532	Samples
NE5532DRE4	ACTIVE	SOIC	D	8	2500	Green (RoHS & no Sb/Br)	CU NIPDAU	Level-1-260C-UNLIM	0 to 70	N5532	Samples
NE5532DRG4	ACTIVE	SOIC	D	8	2500	Green (RoHS & no Sb/Br)	CU NIPDAU	Level-1-260C-UNLIM	0 to 70	N5532	Samples
NE5532IP	OBSOLETI	PDIP	Р	8		TBD	Call TI	Call TI	-40 to 85		
NE5532P	ACTIVE	PDIP	Р	8	50	Pb-Free (RoHS)	CU NIPDAU	N / A for Pkg Type	0 to 70	NE5532P	Samples
NE5532PE4	ACTIVE	PDIP	Р	8	50	Pb-Free (RoHS)	CU NIPDAU	N / A for Pkg Type	0 to 70	NE5532P	Samples



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Orderable Device	Status	Package Type	Package Drawing	Pins	Package Qty	Eco Plan	Lead/Ball Finish	MSL Peak Temp	Op Temp (°C)	Device Marking (4/5)	Sample
NE5532PSR	ACTIVE	SO	PS	8	2000	Green (RoHS & no Sb/Br)	CU NIPDAU	Level-1-260C-UNLIM	0 to 70	N5532	Sample
NE5532PSRE4	ACTIVE	SO	PS	8	2000	Green (RoHS & no Sb/Br)	CU NIPDAU	Level-1-260C-UNLIM	0 to 70	N5532	Sample
NE5532PSRG4	ACTIVE	SO	PS	8	2000	Green (RoHS & no Sb/Br)	CU NIPDAU	Level-1-260C-UNLIM	0 to 70	N5532	Sample
SA5532AD	ACTIVE	SOIC	D	8	75	Green (RoHS & no Sb/Br)	CU NIPDAU	Level-1-260C-UNLIM	-40 to 85	SA5532A	Sample
SA5532ADE4	ACTIVE	SOIC	D	8		TBD	Call TI	Call TI	-40 to 85		Sample
SA5532ADG4	ACTIVE	SOIC	D	8	75	Green (RoHS & no Sb/Br)	CU NIPDAU	Level-1-260C-UNLIM	-40 to 85	SA5532A	Sample
SA5532ADR	ACTIVE	SOIC	D	8	2500	Green (RoHS & no Sb/Br)	CU NIPDAU	Level-1-260C-UNLIM	-40 to 85	SA5532A	Sample
SA5532ADRE4	ACTIVE	SOIC	D	8		TBD	Call TI	Call TI	-40 to 85		Sample
SA5532ADRG4	ACTIVE	SOIC	D	8	2500	Green (RoHS & no Sb/Br)	CU NIPDAU	Level-1-260C-UNLIM	-40 to 85	SA5532A	Sample
SA5532AP	ACTIVE	PDIP	Р	8	50	Pb-Free (RoHS)	CU NIPDAU	N / A for Pkg Type	-40 to 85	SA5532AP	Sample
SA5532APE4	ACTIVE	PDIP	Р	8	50	Pb-Free (RoHS)	CU NIPDAU	N / A for Pkg Type	-40 to 85	SA5532AP	Sample
SA5532D	ACTIVE	SOIC	D	8	75	Green (RoHS & no Sb/Br)	CU NIPDAU	Level-1-260C-UNLIM	-40 to 85	SA5532	Sample
SA5532DE4	ACTIVE	SOIC	D	8		TBD	Call TI	Call TI	-40 to 85		Sample
SA5532DG4	ACTIVE	SOIC	D	8		TBD	Call TI	Call TI	-40 to 85		Sample
SA5532DR	ACTIVE	SOIC	D	8	2500	Green (RoHS & no Sb/Br)	CU NIPDAU	Level-1-260C-UNLIM	-40 to 85	SA5532	Sample
SA5532DRE4	ACTIVE	SOIC	D	8		TBD	Call TI	Call TI	-40 to 85		Sample
SA5532DRG4	ACTIVE	SOIC	D	8	2500	Green (RoHS & no Sb/Br)	CU NIPDAU	Level-1-260C-UNLIM	-40 to 85	SA5532	Sample
SA5532P	ACTIVE	PDIP	Р	8	50	Pb-Free (RoHS)	CU NIPDAU	N / A for Pkg Type	-40 to 85	SA5532P	Sample
SA5532PE4	ACTIVE	PDIP	Р	8	50	Pb-Free (RoHS)	CU NIPDAU	N / A for Pkg Type	-40 to 85	SA5532P	Sample



## PACKAGE OPTION ADDENDUM

10-Jun-2014

(1) The marketing status values are defined as follows:

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ACTIVE: Product device recommended for new designs.

LIFEBUY: TI has announced that the device will be discontinued, and a lifetime-buy period is in effect.

NRND: Not recommended for new designs. Device is in production to support existing customers, but TI does not recommend using this part in a new design.

PREVIEW: Device has been announced but is not in production. Samples may or may not be available.

**OBSOLETE:** TI has discontinued the production of the device.

(2) Eco Plan - The planned eco-friendly classification: Pb-Free (RoHS), Pb-Free (RoHS Exempt), or Green (RoHS & no Sb/Br) - please check http://www.ti.com/productcontent for the latest availability information and additional product content details.

**TBD:** The Pb-Free/Green conversion plan has not been defined.

**Pb-Free** (RoHS): TI's terms "Lead-Free" or "Pb-Free" mean semiconductor products that are compatible with the current RoHS requirements for all 6 substances, including the requirement that lead not exceed 0.1% by weight in homogeneous materials. Where designed to be soldered at high temperatures, TI Pb-Free products are suitable for use in specified lead-free processes.

**Pb-Free (RoHS Exempt):** This component has a RoHS exemption for either 1) lead-based flip-chip solder bumps used between the die and package, or 2) lead-based die adhesive used between the die and leadframe. The component is otherwise considered Pb-Free (RoHS compatible) as defined above.

Green (RoHS & no Sb/Br): TI defines "Green" to mean Pb-Free (RoHS compatible), and free of Bromine (Br) and Antimony (Sb) based flame retardants (Br or Sb do not exceed 0.1% by weight in homogeneous material)

- (3) MSL, Peak Temp. The Moisture Sensitivity Level rating according to the JEDEC industry standard classifications, and peak solder temperature.
- (4) There may be additional marking, which relates to the logo, the lot trace code information, or the environmental category on the device.
- (5) Multiple Device Markings will be inside parentheses. Only one Device Marking contained in parentheses and separated by a "~" will appear on a device. If a line is indented then it is a continuation of the previous line and the two combined represent the entire Device Marking for that device.
- (6) Lead/Ball Finish Orderable Devices may have multiple material finish options. Finish options are separated by a vertical ruled line. Lead/Ball Finish values may wrap to two lines if the finish value exceeds the maximum column width.

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PACKAGE MATERIALS INFORMATION

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# TAPE AND REEL INFORMATION





	Dimension designed to accommodate the component width
B0	Dimension designed to accommodate the component length
K0	Dimension designed to accommodate the component thickness
W	Overall width of the carrier tape
P1	Pitch between successive cavity centers

### QUADRANT ASSIGNMENTS FOR PIN 1 ORIENTATION IN TAPE



### \*All dimensions are nominal

Device	Package Type	Package Drawing		SPQ	Reel Diameter (mm)	Reel Width W1 (mm)	A0 (mm)	B0 (mm)	K0 (mm)	P1 (mm)	W (mm)	Pin1 Quadrant
NE5532ADR	SOIC	D	8	2500	330.0	12.4	6.4	5.2	2.1	8.0	12.0	Q1
NE5532APSR	SO	PS	8	2000	330.0	16.4	8.2	6.6	2.5	12.0	16.0	Q1
NE5532DR	SOIC	D	8	2500	330.0	12.8	6.4	5.2	2.1	8.0	12.0	Q1
NE5532DR	SOIC	D	8	2500	330.0	12.4	6.4	5.2	2.1	8.0	12.0	Q1
NE5532DRG4	SOIC	D	8	2500	330.0	12.4	6.4	5.2	2.1	8.0	12.0	Q1
NE5532PSR	SO	PS	8	2000	330.0	16.4	8.2	6.6	2.5	12.0	16.0	Q1
SA5532ADR	SOIC	D	8	2500	330.0	12.4	6.4	5.2	2.1	8.0	12.0	Q1
SA5532DR	SOIC	D	8	2500	330.0	12.4	6.4	5.2	2.1	8.0	12.0	Q1

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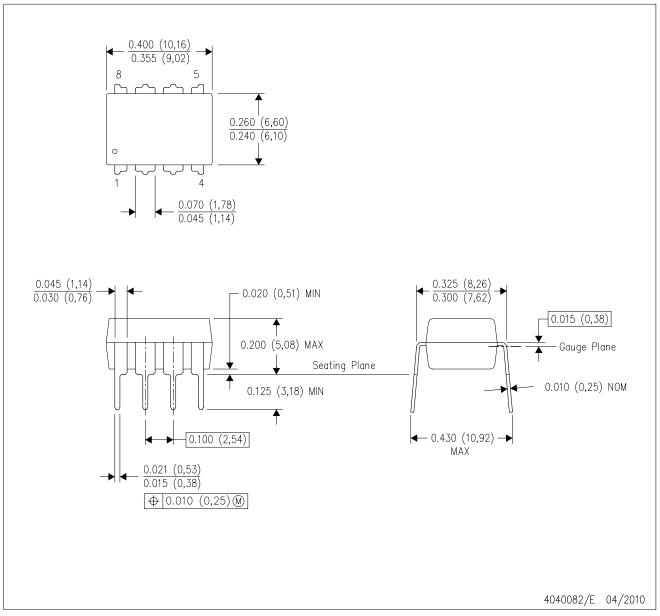


\*All dimensions are nominal

Device	Package Type	Package Drawing	Pins	SPQ	Length (mm)	Width (mm)	Height (mm)
NE5532ADR	SOIC	D	8	2500	340.5	338.1	20.6
NE5532APSR	so	PS	8	2000	367.0	367.0	38.0
NE5532DR	SOIC	D	8	2500	364.0	364.0	27.0
NE5532DR	SOIC	D	8	2500	340.5	338.1	20.6
NE5532DRG4	SOIC	D	8	2500	340.5	338.1	20.6
NE5532PSR	SO	PS	8	2000	367.0	367.0	38.0
SA5532ADR	SOIC	D	8	2500	340.5	338.1	20.6
SA5532DR	SOIC	D	8	2500	340.5	338.1	20.6

# P (R-PDIP-T8)

# PLASTIC DUAL-IN-LINE PACKAGE



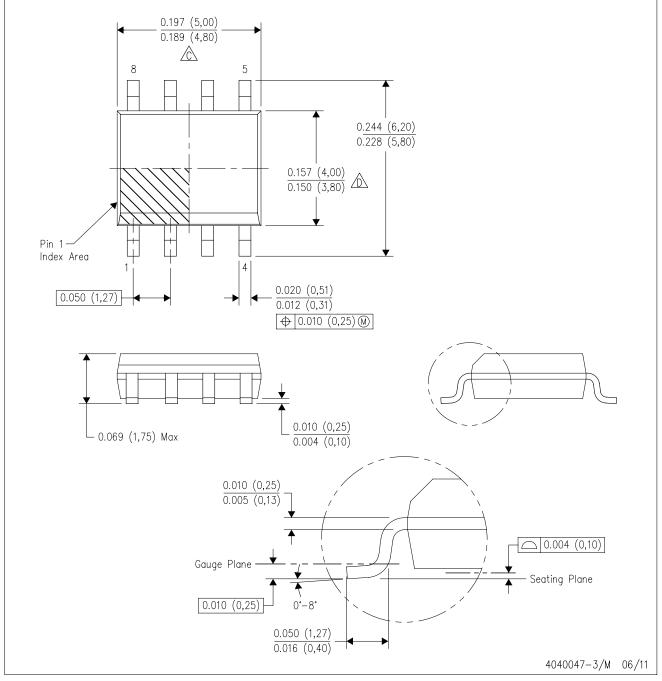
NOTES:

- A. All linear dimensions are in inches (millimeters).
- B. This drawing is subject to change without notice.
- C. Falls within JEDEC MS-001 variation BA.



# D (R-PDSO-G8)

## PLASTIC SMALL OUTLINE



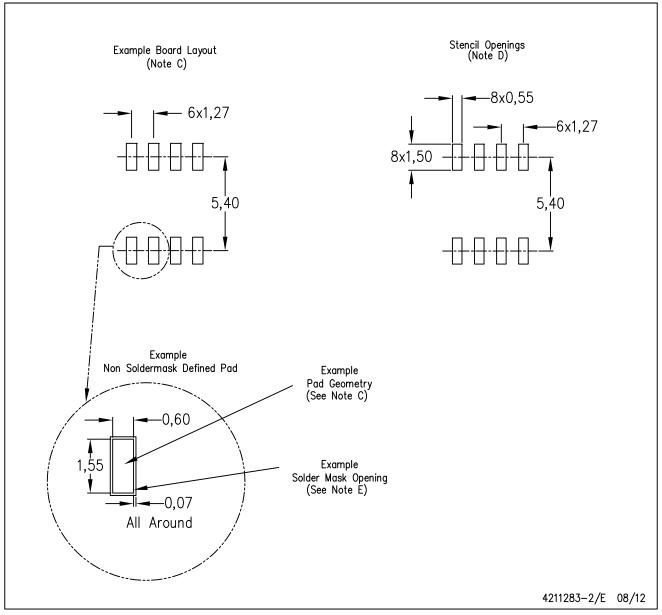
NOTES:

- A. All linear dimensions are in inches (millimeters).
- B. This drawing is subject to change without notice.
- Body length does not include mold flash, protrusions, or gate burrs. Mold flash, protrusions, or gate burrs shall not exceed 0.006 (0,15) each side.
- Body width does not include interlead flash. Interlead flash shall not exceed 0.017 (0,43) each side.
- E. Reference JEDEC MS-012 variation AA.



# D (R-PDSO-G8)

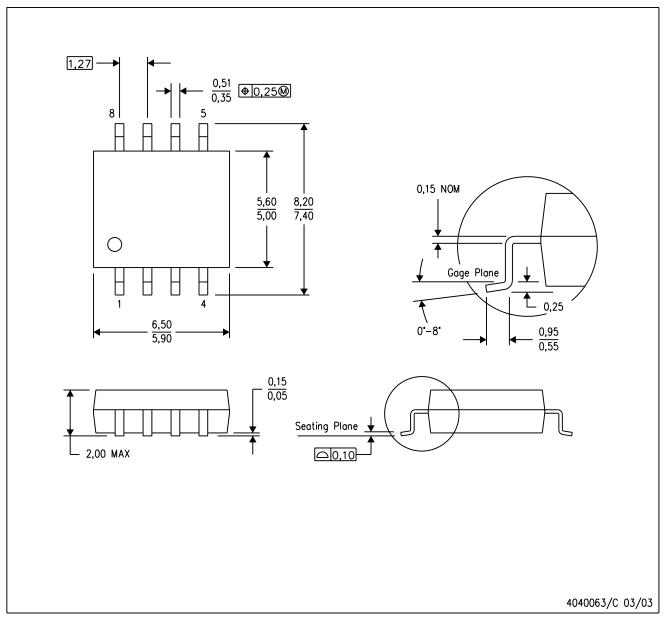
# PLASTIC SMALL OUTLINE



NOTES:

- A. All linear dimensions are in millimeters.
- B. This drawing is subject to change without notice.
- C. Publication IPC-7351 is recommended for alternate designs.
- D. Laser cutting apertures with trapezoidal walls and also rounding corners will offer better paste release. Customers should contact their board assembly site for stencil design recommendations. Refer to IPC-7525 for other stencil recommendations.
- E. Customers should contact their board fabrication site for solder mask tolerances between and around signal pads.





NOTES: A. All linear dimensions are in millimeters.

B. This drawing is subject to change without notice.

C. Body dimensions do not include mold flash or protrusion, not to exceed 0,15.



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